BCM856BS; BCM856BS/DG BCM856DS; BCM856DS/DG

PNP/PNP matched double transistors

Rev. 01 — 7 August 2008

Product data sheet

1. Product profile

1.1 General description

PNP/PNP matched double transistors in small Surface-Mounted Device (SMD) plastic packages. The transistors are fully isolated internally.

Table 1.Product overview

Type number	Package		Package configuration
	Nexperia	JEITA	
BCM856BS	SOT363	SC-88	very small
BCM856BS/DG			
BCM856DS	SOT457	SC-74	small
BCM856DS/DG			

1.2 Features

- Current gain matching
- Base-emitter voltage matching
- Drop-in replacement for standard double transistors
- AEC-Q101 qualified

1.3 Applications

- Current mirror
- Differential amplifier

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Per transis	stor					
V _{CEO}	collector-emitter voltage	open base	-	-	-65	V
I _C	collector current		-	-	-100	mA
h _{FE}	DC current gain	V _{CE} = –5 V; I _C = –2 mA	200	290	450	

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Table 2.	QUICK reference dat	acontinued				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device)					
h _{FE1} /h _{FE2}	h _{FE} matching	$V_{CE} = -5 V;$ $I_{C} = -2 mA$	[<u>1]</u> 0.9	1	-	
$V_{BE1} - V_{BE2}$	V_{BE} matching	$V_{CE} = -5 V;$ $I_{C} = -2 mA$	<u>[2]</u> _	-	2	mV

 Table 2.
 Quick reference data ...continued

 $\begin{tabular}{ll} [1] & The smaller of the two values is taken as the numerator. \end{tabular}$

[2] The smaller of the two values is subtracted from the larger value.

2. Pinning information

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Table 3.	Pinning	
Pin	Description	Simplified outline Graphic symbol
1	emitter TR1	
2	base TR1	
3	collector TR2	
4	emitter TR2	
5	base TR2	
6	collector TR1	001aab555
		sym018

3. Ordering information

Table 4. Ordering information					
Type number	Package	Package			
	Name	Description	Version		
BCM856BS	SC-88	plastic surface-mounted package; 6 leads	SOT363		
BCM856BS/DG					
BCM856DS	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457		
BCM856DS/DG					

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4. Marking

Table 5. Marking codes	
Type number	Marking code ^[1]
BCM856BS	*BS
BCM856BS/DG	PB*
BCM856DS	DS
BCM856DS/DG	R9

- [1] * = -: made in Hong Kong
 - * = p: made in Hong Kong
 - * = t: made in Malaysia
 - * = W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per trans	istor				
V _{CBO}	collector-base voltage	open emitter	-	-80	V
V _{CEO}	collector-emitter voltage	open base	-	-65	V
V_{EBO}	emitter-base voltage	open collector	-	-5	V
I _C	collector current		-	-100	mA
I _{CM}	peak collector current	single pulse; $t_p \leq 1 ms$	-	-200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	BCM856BS (SOT363) BCM856BS/DG (SOT363)		<u>[1]</u> _	200	mW
	BCM856DS (SOT457) BCM856DS/DG (SOT457)		<u>[1]</u> -	250	mW
Per devic	ce in the second se				
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	BCM856BS (SOT363) BCM856BS/DG (SOT363)		<u>[1]</u> -	300	mW
	BCM856DS (SOT457) BCM856DS/DG (SOT457)		<u>[1]</u> _	380	mW
Тj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	sistor					
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	BCM856BS (SOT363) BCM856BS/DG (SOT363)		<u>[1]</u> -	-	625	K/W
	BCM856DS (SOT457) BCM856DS/DG (SOT457)		<u>[1]</u> -	-	500	K/W
Per devi	се					
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	BCM856BS (SOT363) BCM856BS/DG (SOT363)		<u>[1]</u> -	-	416	K/W
	BCM856DS (SOT457) BCM856DS/DG (SOT457)		<u>[1]</u> _	-	328	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 8.Characteristics

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transi	stor					
I _{CBO}	collector-base cut-off current	V _{CB} = -30 V; I _E = 0 A	-	-	-15	nA
		V _{CB} = -30 V; I _E = 0 A; T _j = 150 °C	-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 V;$ $I_C = 0 A$	-	-	-100	nA
h _{FE}	DC current gain	V _{CE} = –5 V; I _C = –10 μA	-	250	-	
		$V_{CE} = -5 V;$ $I_C = -2 mA$	200	290	450	
V _{CEsat}	collector-emitter saturation voltage	I _C = –10 mA; I _B = –0.5 mA	-	-50	-200	mV
		$I_{\rm C}$ = -100 mA; $I_{\rm B}$ = -5 mA	-	-200	-400	mV
V _{BEsat}	base-emitter saturation voltage	$I_{\rm C} = -10 \text{ mA};$ $I_{\rm B} = -0.5 \text{ mA}$	<u>[1]</u> _	-760	-	mV
		l _C = –100 mA; l _B = –5 mA	<u>[1]</u> -	-920	-	mV

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{BE}	base-emitter voltage	$V_{CE} = -5 V;$ $I_C = -2 mA$	<u>[2]</u> –600	-650	-700	mV
		$V_{CE} = -5 V;$ $I_{C} = -10 mA$	[2] _	-	-760	mV
C _c	collector capacitance	$V_{CB} = -10 \text{ V};$ $I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	2.2	pF
C _e	emitter capacitance	$\label{eq:Veb} \begin{array}{l} V_{EB} = -0.5 \; V; \\ I_{C} = i_{c} = 0 \; A; \\ f = 1 \; MHz \end{array}$	-	10	-	pF
f _T	transition frequency	$V_{CE} = -5 V;$ $I_{C} = -10 mA;$ f = 100 MHz	100	175	-	MHz
NF	noise figure	$V_{CE} = -5 V;$ $I_C = -0.2 mA;$ $R_S = 2 k\Omega;$ f = 10 Hz to 15.7 kHz	-	1.6	-	dB
		$V_{CE} = -5 V;$ $I_{C} = -0.2 mA;$ $R_{S} = 2 k\Omega;$ f = 1 kHz; B = 200 Hz	-	3.1	-	dB
Per device						
h _{FE1} /h _{FE2}	h _{FE} matching	$V_{CE} = -5 V;$ $I_{C} = -2 mA$	<u>[3]</u> 0.9	1	-	
$V_{BE1} - V_{BE2}$	V _{BE} matching	V _{CE} = -5 V; I _C = -2 mA	<u>[4]</u> _	-	2	mV

Table 8. Characteristics ...continued

 $T_{omb} = 25 \,^{\circ}C$ unless otherwise specified.

[1] V_{BEsat} decreases by about 1.7 mV/K with increasing temperature.

[2] V_{BE} decreases by about 2 mV/K with increasing temperature.

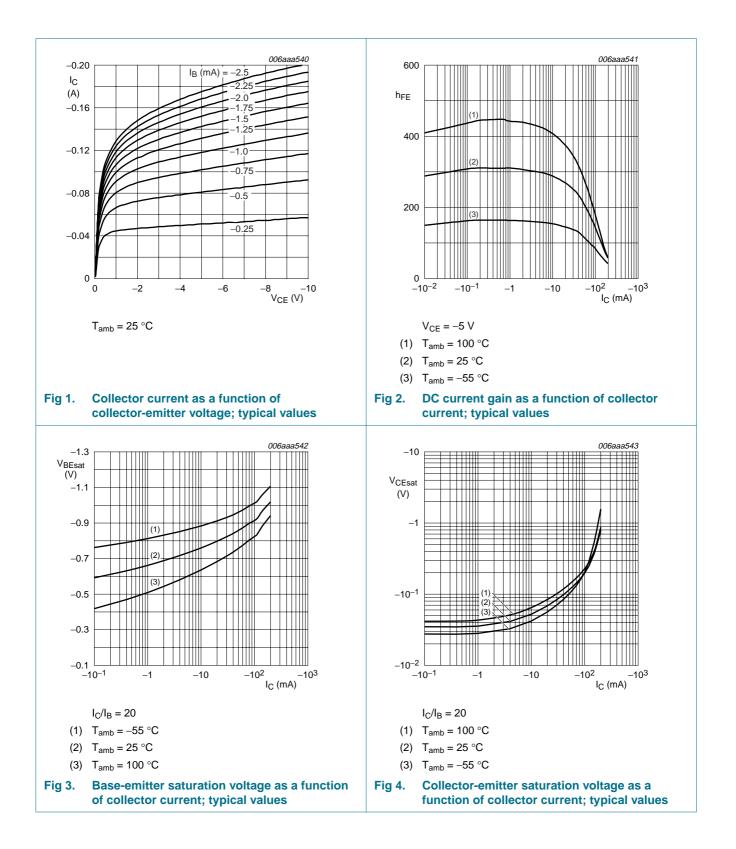
[3] The smaller of the two values is taken as the numerator.

[4] The smaller of the two values is subtracted from the larger value.

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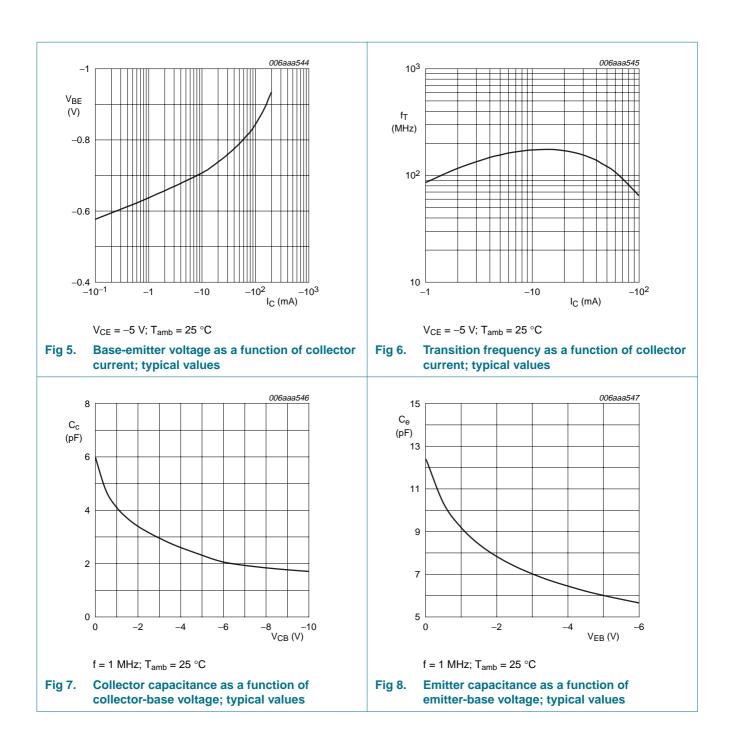


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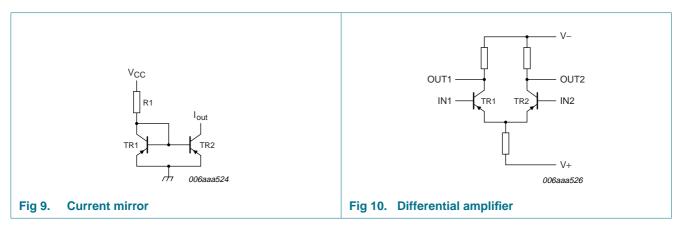
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8. Application information

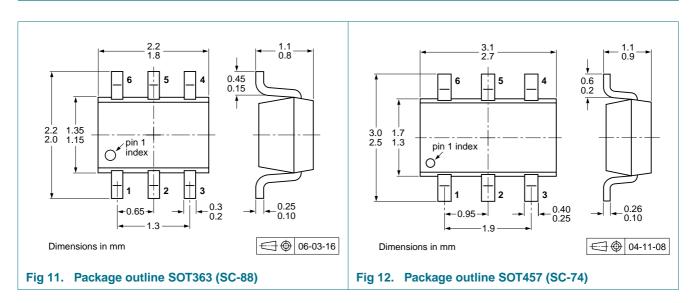


9. Test information

9.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

10. Package outline



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11. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

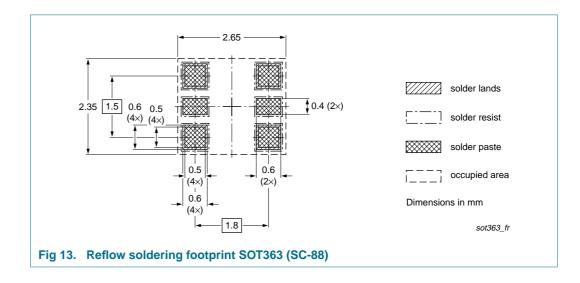
Type number	Package	Description	Packing c	uantity
			3000	10000
BCM856BS	SOT363	4 mm pitch, 8 mm tape and reel; T1	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	-125	-165
BCM856BS/DG	SOT363	4 mm pitch, 8 mm tape and reel; T1	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	-125	-165
BCM856DS	SOT457	4 mm pitch, 8 mm tape and reel; T1	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	-125	-165
BCM856DS/DG	SOT457	4 mm pitch, 8 mm tape and reel; T1	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	-125	-165

[1] For further information and the availability of packing methods, see <u>Section 15</u>.

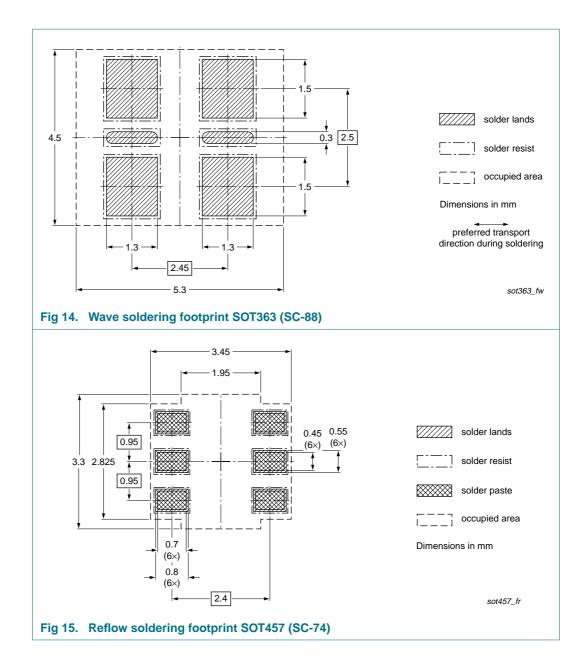
[2] T1: normal taping

[3] T2: reverse taping

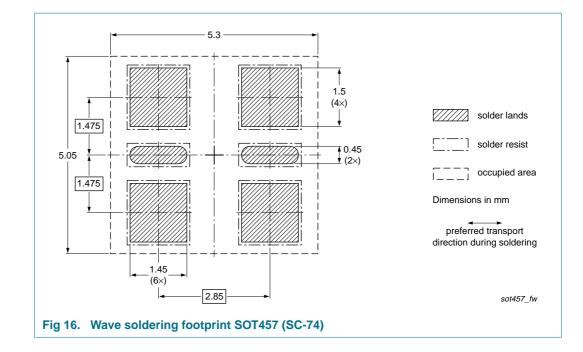
12. Soldering



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13. Revision history

Table 10. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
BCM856BS_BCM856DS_1	20080807	Product data sheet	-	-

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14. Legal information

14.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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